



Product Summary

BV _{DSS}	R _{DS(ON)} max	l _D max T _A = +25°C
20V	56mΩ @ V _{GS} = 4.5V	2.8A
	65mΩ @ V _{GS} = 2.5V	2.6A
	93mΩ @ V _{GS} = 1.8V	2.2A
	140mΩ @ V _{GS} = 1.5V	1.8A

Description and Applications

This new generation MOSFET has been designed to minimize the onstate resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications:

- General Purpose Interfacing Switch
- Power Management Functions
- DC-DC Converters
- Analog Switch

20V N-CHANNEL ENHANCEMENT MODE MOSFET

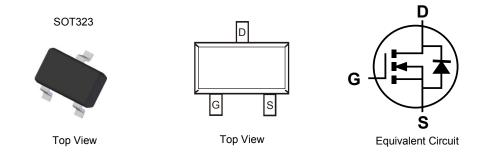
Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN2065UWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Alloy42 Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.027 grams (Approximate)



Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
DMN2065UWQ-7	Automotive	SOT323	3,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

	DMH	ΥM
Ъ		

DMH = Product Type Marking Code YM or \overline{Y} M = Date Code Marking Y or \overline{Y} = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key												
Year	2011		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	Y			J	K	L	М	Ν	0	Р	R	S
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	20	V		
Gate-Source Voltage			V _{GSS}	±12	V
	Steady State	T _A = +25°C T _A = +70°C	ID	2.8 2.3	А
Continuous Drain Current (Note 6) V_{GS} = 4.5V	t<10s	T _A = +25°C T _A = +70°C	ID	3.1 2.6	А
	Steady State	T _A = +25°C T _A = +70°C	ID	2.2 1.7	А
Continuous Drain Current (Note 6) V _{GS} = 1.8V	t<10s	T _A = +25°C T _A = +70°C	ID	2.4 1.9	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	I _{DM}	30	А		
Maximum Body Diode Forward Current (Note 5)	ls	1.2	А		

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.43	W
Thermal Registerion Junction to Ambient (Note 5)	Steady State	Р	296	°C/W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ extsf{ heta}JA}$	252	°C/W
Total Power Dissipation (Note 6)		PD	0.7	W
Thermal Resistance, Junction to Ambient (Note 6) Steady State t<10s		P	178	°C/W
		R _{0JA}	151	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

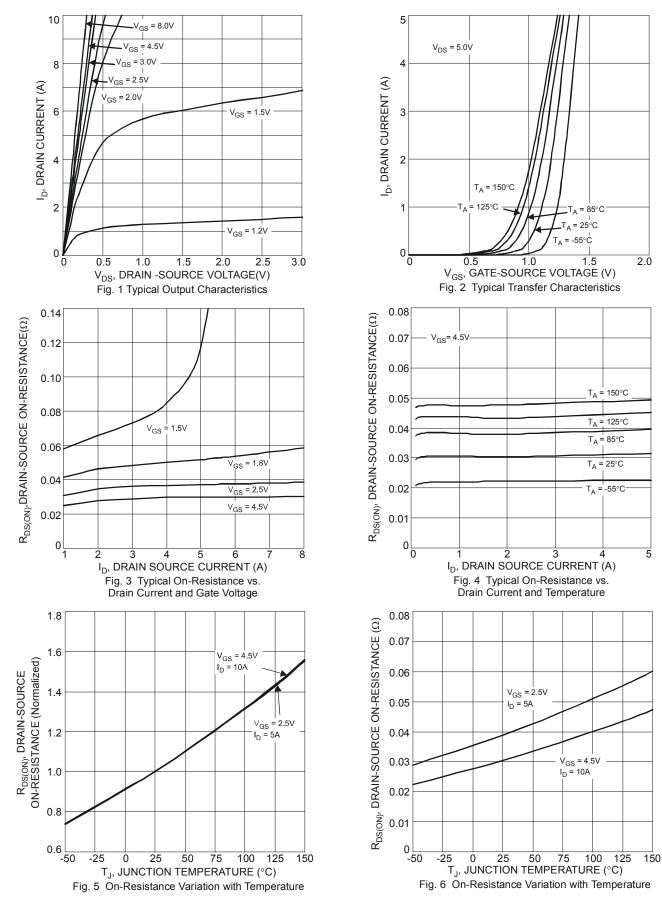
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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)			1			I
Drain-Source Breakdown Voltage	BV _{DSS}	20	—		V	V_{GS} = 0V, I_D = 1mA
Zero Gate Voltage Drain Current $@T_C = +25^{\circ}C$	I _{DSS}	—	—	1	μA	V_{DS} = 20V, V_{GS} = 0V
Gate-Source Leakage	IGSS	_	—	±1	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)				-	-	
Gate Threshold Voltage	V _{GS(th)}	0.35		1	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
			52	56		V_{GS} = 4.5V, I_{D} = 2A
Static Drain-Source On-Resistance	Dealer		59	65	mΩ	V _{GS} = 2.5V, I _D = 2A
	R _{DS(on)}		60	93	11122	V _{GS} = 1.8V, I _D = 1A
		_	75	140		V _{GS} = 1.5V, I _D = 0.5A
Forward Transfer Admittance	Y _{fs}	_	7	_	S	V _{DS} = 5V, I _D = 3.8A
Diode Forward Voltage	V _{SD}	_	0.7	1	V	$V_{GS} = 0V, I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		400	_	pF	
Output Capacitance	Coss	_	73.8	_	pF	V _{DS} = 10V, V _{GS} = 0V, f = 1MHz
Reverse Transfer Capacitance	Crss	_	65.6	_	pF	
Total Gate Charge	Qg	_	5.4	_	nC	
Gate-Source Charge	Qgs	_	0.7	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Q _{gd}	_	1.4	_	nC	I _D = 6A
Turn-On Delay Time	t _{D(on)}	_	3.5		ns	
Turn-On Rise Time	t _R	_	9.7		ns	V _{DD} = 10V, V _{GS} = 5V,
Turn-Off Delay Time	t _{D(off)}	_	23.8		ns	R _L = 1.7Ω, R _G = 6Ω
Turn-Off Fall Time	t _F	_	7.2		ns	

Notes: 5. Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.

Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



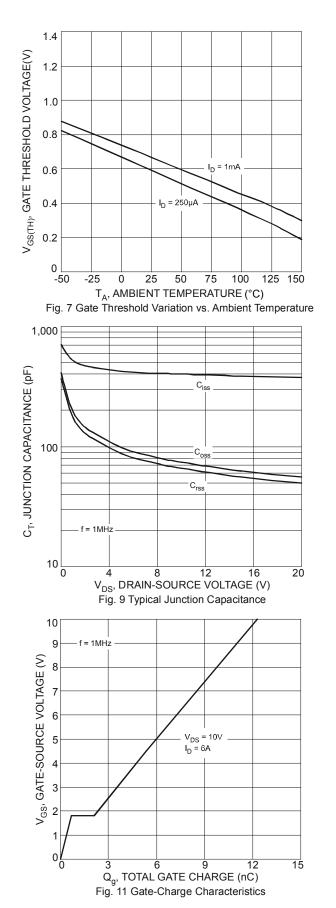
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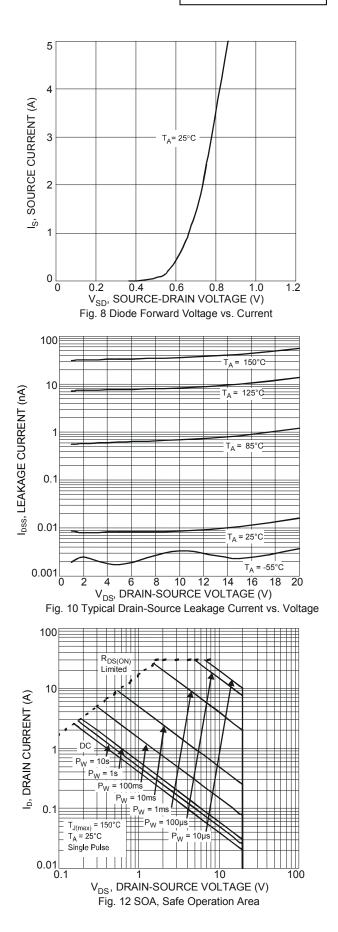


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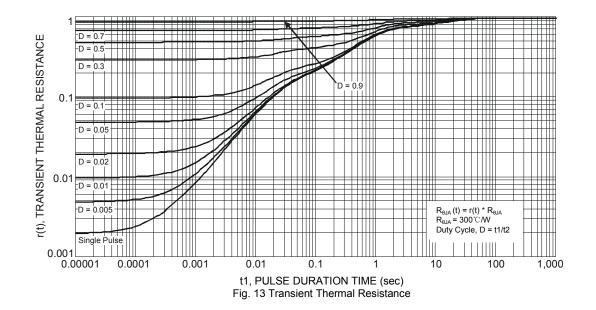






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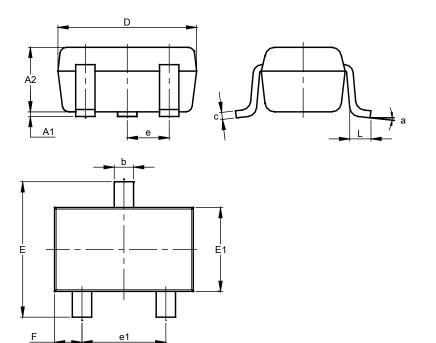




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323

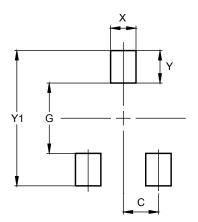


SOT323								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.25	0.40	0.30					
C	0.10	0.18	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	C).650 B	SC					
e1	1.20	1.40	1.30					
F	0.375	0.475	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All	Dimen	sions	in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323



Dimensions	Value (in mm)
С	0.650
G	1.300
X	0.470
Y	0.600
Y1	2.500



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